# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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### MCD26-16io8B

 $= 2 \times 1600 \text{ V}$ 

27 A

1.27 V

 $V_{RRM}$ 

I TAV

VT

### **Thyristor \ Diode Module**

Phase	leg
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Part number MCD26-16io8B



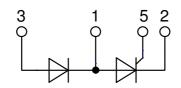
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Backside: isolated **E**72873

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#### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

#### **Applications:**

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

#### Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

#### Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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## LIXYS

## MCD26-16io8B

Rectifier					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Uni
V <sub>RSM/DSM</sub>	max. non-repetitive reverse/forwa		$T_{VJ} = 25^{\circ}C$			1700	\
V <sub>RRM/DRM</sub>	max. repetitive reverse/forward bl	0 0	$T_{VJ} = 25^{\circ}C$			1600	۷
R/D	reverse current, drain current	$V_{R/D} = 1600 V$	$T_{vJ} = 25^{\circ}C$			100	μA
		V <sub>R/D</sub> = 1600 V	$T_{vJ} = 125^{\circ}C$			3	mA
V <sub>T</sub>	forward voltage drop	$I_{T} = 40 \text{ A}$	$T_{vJ} = 25^{\circ}C$			1.27	۷
		$I_{T} = 80 \text{ A}$				1.64	V
		$I_{T} = 40 \text{ A}$	$T_{vJ} = 125^{\circ}C$			1.27	٧
		Ι <sub>T</sub> = 80 A				1.65	V
ITAV	average forward current	$T_c = 85^{\circ}C$	T <sub>vJ</sub> = 125°C			27	A
T(RMS)	RMS forward current	180° sine				42	A
V <sub>T0</sub>	threshold voltage		T <sub>v.i</sub> = 125°C			0.85	V
r <sub>T</sub>	slope resistance } for power lo	oss calculation only				11	mΩ
<b>R</b> <sub>thJC</sub>	thermal resistance junction to cas	6e				0.88	K/W
R <sub>thCH</sub>	thermal resistance case to heatsi				0.20		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$		00	115	W
	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{\rm vi} = 45^{\circ}\rm C$			520	A
ISM		t = 8,3 ms; (60 Hz), sine	$V_{\rm N} = 0 V$			560	A
		t = 0,0  ms; (50  Hz),  sine t = 10  ms; (50  Hz),  sine	T <sub>v.1</sub> = 125°C			440	A
		t = 8,3 ms; (60 Hz), sine	$V_{\rm R} = 0 V$			475	A
124	value for fusing	t = 0.5  ms; (50  Hz),  sine	$\frac{v_{R}}{T_{VJ}} = 45^{\circ}C$				 
l²t	value for fusing					1.35	kA²s
		t = 8,3 ms; (60 Hz), sine	$V_{\rm R} = 0 V$			1.31	kA <sup>2</sup> s
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 125 ^{\circ}C$			970	A²s
_		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			940	A <sup>2</sup> s
C	junction capacitance	$V_{R} = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		22		pF
P <sub>GM</sub>	max. gate power dissipation	t <sub>P</sub> = 30 μs	$T_c = 125^{\circ}C$			10	W
		t <sub>P</sub> = 300 μs				5	W
P <sub>GAV</sub>	average gate power dissipation					0.5	W
(di/dt) <sub>cr</sub>	critical rate of rise of current	$T_{vJ} = 125 ^{\circ}C; f = 50  Hz$ re	epetitive, $I_{T} = 45 \text{ A}$			150	A/μs
		$t_{P}$ = 200 µs; di <sub>G</sub> /dt = 0.45 A/µs; -					
		$I_{G} = 0.45 \text{ A}; \text{ V} = \frac{2}{3} \text{ V}_{DRM}$ no	on-repet., $I_{T} = 27 \text{ A}$			500	A/μs
(dv/dt) <sub>cr</sub>	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{vJ} = 125^{\circ}C$			1000	V/µs
		R <sub>GK</sub> = ∞; method 1 (linear volta	ge rise)				
V <sub>GT</sub>	gate trigger voltage	$V_{\rm D} = 6 \text{ V}$	$T_{vJ} = 25^{\circ}C$			1.5	V
			$T_{vJ} = -40 ^{\circ}\text{C}$			1.6	V
I <sub>GT</sub>	gate trigger current	$V_{D} = 6 V$	$T_{vJ} = 25^{\circ}C$			100	mA
u.		5	$T_{vJ} = -40^{\circ}C$			200	mA
V <sub>gd</sub>	gate non-trigger voltage	$V_{D} = \frac{2}{3} V_{DBM}$	$T_{VJ} = 125^{\circ}C$			0.2	V
I <sub>GD</sub>	gate non-trigger current		· VJ · _ • •			10	mA
	latching current	t <sub>p</sub> = 10 μs	$T_{vJ} = 25 \degree C$			450	mA
I.						-100	
1	holding current	$I_{\rm G} = 0.45 \text{A};  \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu\text{s}}$ $V_{\rm D} = 6 \text{V}  \text{R}_{\rm GK} = \infty$	$T_{vJ} = 25 ^{\circ}\text{C}$			200	m^
I <sub>H</sub>	holding current						mA
t <sub>gd</sub>	gate controlled delay time	$V_{\rm D} = \frac{1}{2} V_{\rm DRM}$	$T_{vJ} = 25 \degree C$			2	μs
		$I_{\rm G} = 0.45 \rm{A};  di_{\rm G}/dt = 0.45 \rm{A}/\mu s$					
t <sub>q</sub>	turn-off time	$V_{R} = 100 \text{ V}; I_{T} = 20 \text{ A}; \text{ V} = 20 \text{ A}$			150		με
		di/dt = 10 A/µs dv/dt = 20 V	/μs t <sub>p</sub> = 200 μs				   

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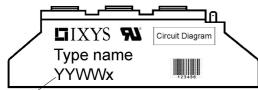
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## LIXYS

### MCD26-16io8B

Package	TO-240AA				F	Ratings	6	
Symbol	Definition	Conditions			min.	typ.	max.	Unit
	RMS current	per terminal					200	Α
T <sub>vj</sub>	virtual junction temperature	)			-40		125	°C
T <sub>op</sub>	operation temperature				-40		100	°C
T <sub>stg</sub>	storage temperature				-40		125	°C
Weight						81		g
M <sub>D</sub>	mounting torque				2.5		4	Nm
M <sub>T</sub>	terminal torque				2.5		4	Nm
d <sub>Spp/App</sub>	creepage distance on surface   striking distance through a		terminal to terminal	13.0	9.7			mm
<b>d</b> <sub>Spb/Apb</sub>			terminal to backside	16.0	16.0			mm
V	isolation voltage	t = 1 second			3600			V
		t = 1 minute	50/60 Hz, RMS; liso∟ ≤ 1 mA		3000			V



Date Code

ſ	Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
	Standard	MCD26-16io8B	MCD26-16io8B	Box	36	453277

Similar Part	Package	Voltage class
MCMA35PD1600TB	TO-240AA-1B	1600
MCMA50PD1600TB	TO-240AA-1B	1600

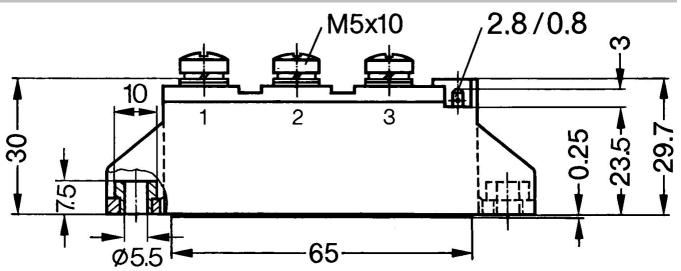
Equivalent Circuits for Simulation			* on die level	T <sub>vj</sub> = 125 °C
	⊢R₀_⊢	Thyristor		
V <sub>0 max</sub>	threshold voltage	0.85		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	9.8		mΩ

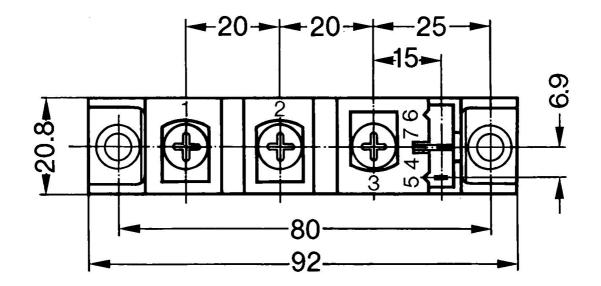
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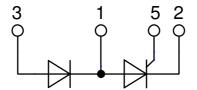
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Outlines TO-240AA

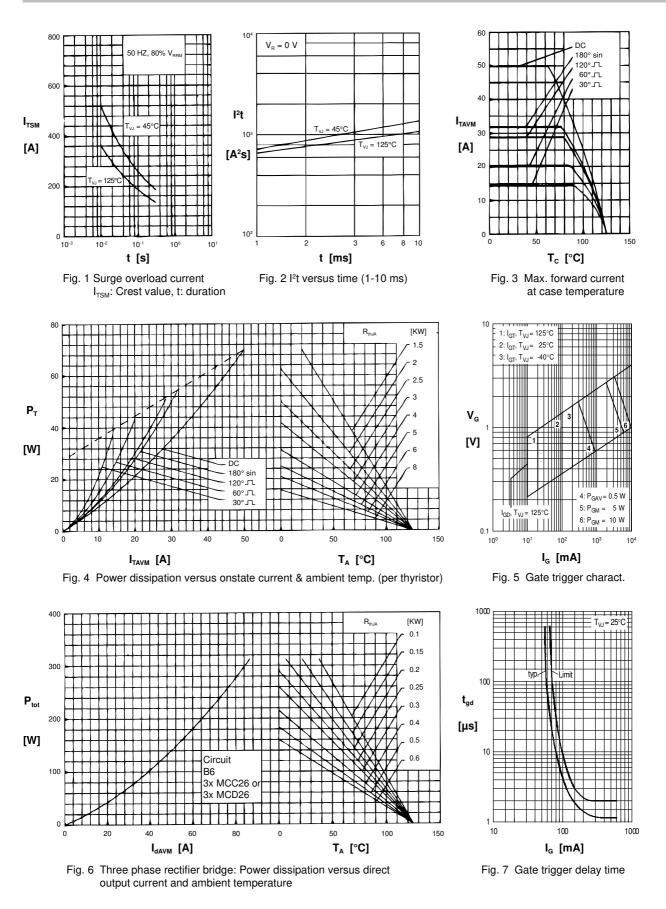






## LIXYS

### Thyristor

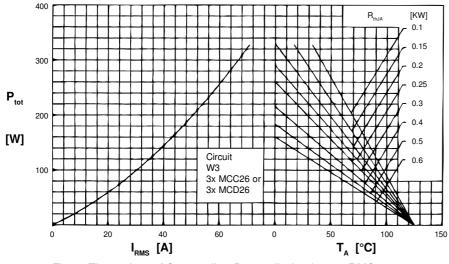


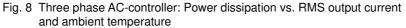
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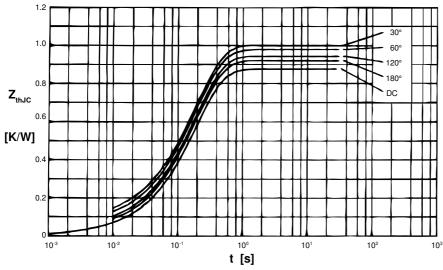
### MCD26-16io8B

## LIXYS

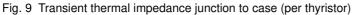
### Rectifier

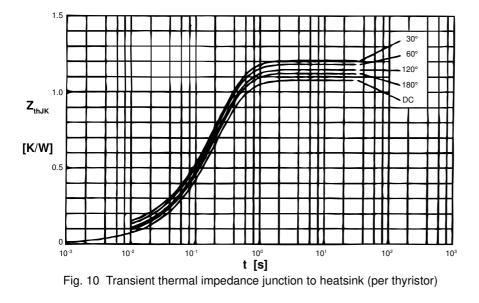






${\rm R}_{\rm thJC}$ for various conduction angles d:					
	d R <sub>t</sub>	<sub>hJC</sub> [K/W]			
	DC	0.88			
	180°	0.92			
	120°	0.95			
	60°	0.98			
	30°	1.01			
Cor	Constants for $Z_{th,IC}$ calculation:				
i	R <sub>thi</sub> [K/W	] t <sub>i</sub> [s]			
1	0.019	0.0031			
2	0.029	0.0216			
3	0.832	0.1910			





R <sub>th</sub>	<sub>к</sub> for vario	us conduction angles d:				
	d R <sub>th</sub>	<sub>JK</sub> [K/W]				
	DC	1.08				
	180°	1.12				
	120°	1.15				
	60°	1.18				
	30°	1.21				
Co	Constants for $Z_{thJK}$ calculation:					
i	R <sub>thi</sub> [K/W]	t <sub>i</sub> [s]				
1	0.019	0.0031				
2	0.029	0.0216				
3	0.832	0.1910				
4	0.200	0.4500				

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